NSN 5961-01-058-6627

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-058-6627 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** Between 0.500 inches and 0.750 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-72 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 35.0 drain to gate voltage and 35.0 drain to source voltage and -35.0 gate to source voltage **Current Rating Per Characteristic:** 10.00 milliamperes gate current **Power Rating Per Characteristic:** 300.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 4 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/428 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

Fiig:

A110a0